

## Silicon Carbide Schottky Barrier Diode



#### Features

- Temperature Independent Switching Behavior
- High Surge Current Capability
- Competitive VF 1.3V at rated current
- Low Conduction Loss
- Zero Reverse Recovery
- High junction temperature 175 °C
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

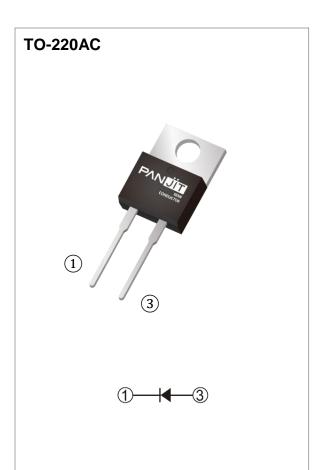
- Case: TO-220AC molded plastic
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 1.8903 grams

#### Application

• PFC, UPS, PV Inverter, EV Charging Station, Welder

## Maximum Ratings and Thermal Characteristics (Tc = 25 °C unless otherwise specified)

PARAMETE	SYMBOL	LIMIT	UNITS		
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	650	V		
DC Blocking Voltage	V <sub>DC</sub>	650	V		
Continuous Forward Current	T <sub>C</sub> = 155 °C	I <sub>F</sub>	16	А	
Repetitive Peak Surge Current	$T_C= 25 \circ C$ , $t_p = 10 ms$		76		
Half Sine Wave, D=0.1	Tc=125 °C , tp =10ms	IFRM	60	A	
Peak Forward Surge Current	$T_{C}=25 \circ C$ , $t_{p}=10ms$		100	А	
Half Sine Wave	$T_C=125 \ ^{\circ}C$ , $t_p =10ms$		88		
Peak Forward Surge Current $t_p = 10us$ , Pulse	Ifsm	904	A		
Maximum Power Dissipation	P <sub>total</sub>	207.5	W		
Operating Junction Temperature Ra	TJ	-55~175	°C		
Storage Temperature Range	T <sub>STG</sub>	-55~175	°C		



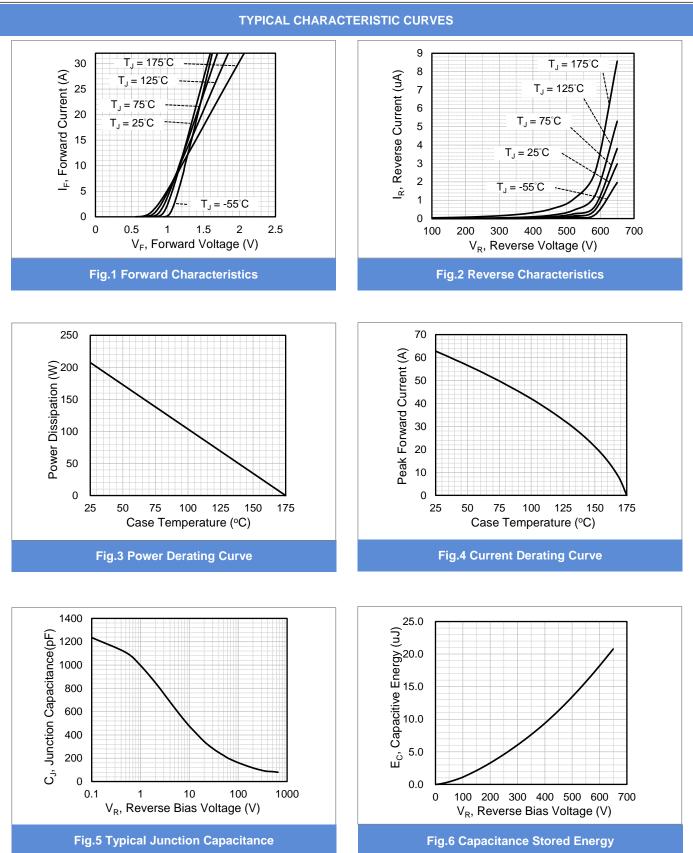


## Electrical Characteristics (Tc = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Forward Voltage Drop	VF	I <sub>F</sub> = 16 A, T <sub>J</sub> = 25 °C	-	1.3	1.6	V	
		I <sub>F</sub> = 16 A, T <sub>J</sub> = 175 °C	-	1.43	-		
Reverse Leakage Current	IR	V <sub>R</sub> = 650 V, T <sub>J</sub> = 25 °C	-	2.9	100	μA	
		V <sub>R</sub> = 650 V, T <sub>J</sub> = 175 °C	-	8	-	μA	
Total Capacitive Charge	Qc	V <sub>R</sub> = 400V	-	58	-	nC	
Total Capacitance	С	V <sub>R</sub> = 1V, f = 100 kHz	-	995	-	pF	
		V <sub>R</sub> = 200V, f = 100 kHz	-	116	-	pF	
		V <sub>R</sub> = 400V, f = 100 kHz	-	87	-	pF	
Capacitance Stored Energy	Ec	V <sub>R</sub> = 400V	-	9.3	-	μJ	
Thermal Resistance	Rejc		-	0.72	-	°C/W	



# PCDP1665GB

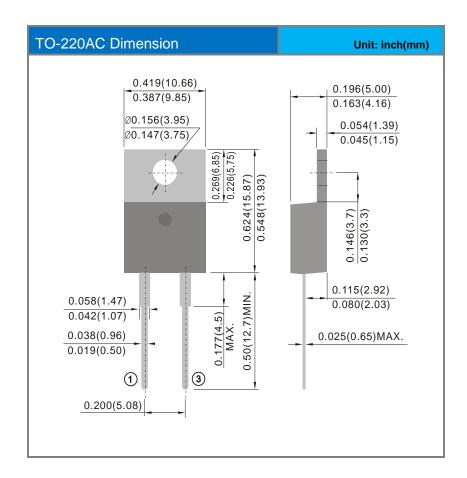


## **Product and Packing Information**



Part No.	Package Type	Packing Type	Marking
PCDP1665GB	TO-220AC	50pcs / Tube	CDP1665GB

### Packaging Information





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